NSN 5961-00-152-7302

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-152-7302 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.085 inches and 0.107 inches **Mounting Method: Terminal** Features Provided: Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.85 breakdown voltage, dc and 5.35 breakdown voltage, dc **Current Rating Per Characteristic:** 75.00 milliamperes dc current in reverse breakdown region and 950.00 milliamperes reverse current, instantaneous **Power Rating Per Characteristic:** 400.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli Fiig: